## INTEGRATED CIRCUITS

## DATA SHEET

# **74ABT00**Quad 2-input NAND gate

Product specification

1995 Sep 18

IC23 Data Handbook





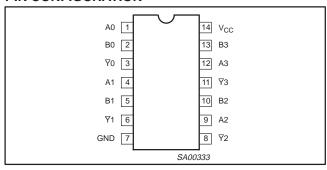
## **Quad 2-input NAND gate**

**74ABT00** 

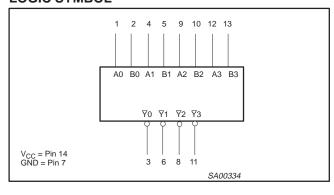
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C; GND = 0V	TYPICAL	UNIT
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay An or Bn to Yn	C <sub>L</sub> = 50pF; V <sub>CC</sub> = 5V	2.5 2.0	ns
t <sub>OSLH</sub> t <sub>OSHL</sub>	Output to Output skew		0.4	ns
C <sub>IN</sub>	Input capacitance	$V_I = 0V \text{ or } V_{CC}$	3	pF
I <sub>CC</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 5.5V	50	μΑ

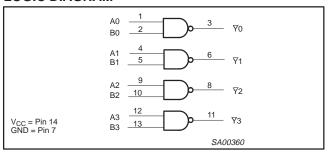
#### **PIN CONFIGURATION**



#### **LOGIC SYMBOL**



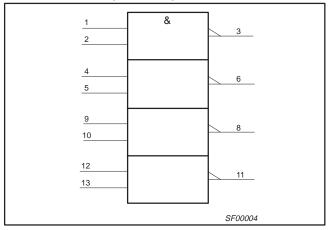
#### **LOGIC DIAGRAM**



#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 4, 5, 9, 10, 12, 13	An-Bn	Data inputs
3, 6, 8, 11	₹n	Data outputs
7	GND	Ground (0V)
14	V <sub>CC</sub>	Positive supply voltage

#### LOGIC SYMBOL (IEEE/IEC)



#### **FUNCTION TABLE**

INP	JTS	OUTPUT
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

#### NOTES:

H = High voltage level
L = Low voltage level

#### ORDERING INFORMATION

OINDERNING INTO ONNINATION				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic DIP	–40°C to +85°C	74ABT00 N	74ABT00 N	SOT27-1
14-Pin plastic SO	-40°C to +85°C	74ABT00 D	74ABT00 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74ABT00 DB	74ABT00 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74ABT00 PW	74ABT00PW DH	SOT402-1

## Quad 2-input NAND gate

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#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-18	mA
V <sub>I</sub>	DC input voltage <sup>3</sup>		-1.2 to +7.0	V
lok	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	output in Off or High state	-0.5 to +5.5	V
I <sub>OUT</sub>	DC output current	output in Low state	40	mA
T <sub>stg</sub>	Storage temperature range		-65 to 150	°C

#### NOTES

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- 3. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
31MBOL	TANAMETER	MIN	MAX	ONIT
V <sub>CC</sub>	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V <sub>CC</sub>	V
V <sub>IH</sub>	High-level input voltage	2.0		V
V <sub>IL</sub>	Low-level input voltage		0.8	V
I <sub>OH</sub>	High-level output current		-15	mA
I <sub>OL</sub>	Low-level output current		20	mA
Δt/Δν	Input transition rise or fall rate	0	5	ns/V
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C

#### DC ELECTRICAL CHARACTERISTICS

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Tai	<sub>mb</sub> = +25	s∘C	T <sub>amb</sub> =	UNIT	
			MIN	TYP	MAX	MIN	MAX	
V <sub>IK</sub>	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V
V <sub>OH</sub>	High-level output voltage	$V_{CC} = 4.5V$ ; $I_{OH} = -15mA$ ; $V_I = V_{IL}$ or $V_{IH}$	2.5	2.9		2.5		V
V <sub>OL</sub>	Low-level output voltage	$V_{CC} = 4.5V$ ; $I_{OL} = 20mA$ ; $V_I = V_{IL}$ or $V_{IH}$		0.35	0.5		0.5	V
I <sub>I</sub>	Input leakage current	$V_{CC} = 5.5V; V_I = GND \text{ or } 5.5V$		±0.01	±1.0		±1.0	μΑ
I <sub>OFF</sub>	Power-off leakage current	$V_{CC} = 0.0V$ ; $V_O$ or $V_I \le 4.5V$		±5.0	±100		±100	μΑ
I <sub>CEX</sub>	Output High leakage current	$V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = GND \text{ or } V_{CC}$		5.0	50		50	μΑ
Io	Output current <sup>1</sup>	$V_{CC} = 5.5V; V_O = 2.5V$	-50	-75	-180	-50	-180	mA
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 5.5V$ ; $V_I = GND$ or $V_{CC}$		2	50		50	μΑ
Δl <sub>CC</sub>	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 5.5V; One data input at 3.4V, other inputs at $V_{CC}$ or GND		0.25	500		500	μА

#### NOTES:

- 1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- 2. This is the increase in supply current for each input at 3.4V.

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## Quad 2-input NAND gate

74ABT00

#### **AC CHARACTERISTICS**

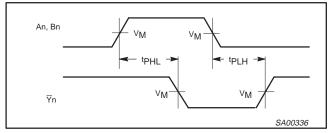
GND = 0V;  $t_R$  =  $t_F$  = 2.5ns;  $C_L$  = 50pF,  $R_L$  = 500 $\Omega$ 

SYMBOL	PARAMETER	WAVEFORM	T <sub>a</sub>	<sub>amb</sub> = +25° ' <sub>CC</sub> = +5.0°	C V	T <sub>amb</sub> = -40° V <sub>CC</sub> = +5	UNIT	
			MIN	TYP	MAX	MIN	MAX	
t <sub>PLH</sub>	Propagation delay An or Bn to Ƴn	1	1.0 1.0	2.5 2.0	3.6 2.8	1.0 1.0	4.1 3.4	ns
toshl toslh	Output to Output skew An or Bn to $\overline{Y}$ n	2		0.4 0.4	0.5 0.5		0.5 0.5	ns

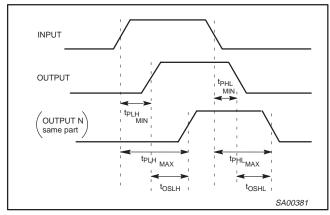
#### NOTE:

#### **AC WAVEFORMS**

 $V_M = 1.5V$ ,  $V_{IN} = GND$  to 3.0V

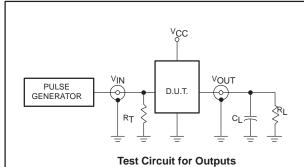


Waveform 1. Propagation delay for inverting outputs



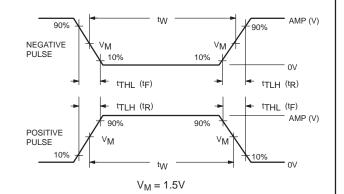
Waveform 2. Common edge skew

#### **TEST CIRCUIT AND WAVEFORMS**



#### **DEFINITIONS**

- R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.
- C<sub>L</sub> = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.
- R<sub>T</sub> = Termination resistance should be equal to Z<sub>OUT</sub> of pulse generators.



#### Input Pulse Definition

FAMILY	IN	INPUT PULSE REQUIREMENTS											
FAMILY	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>								
74ABT	3.0V	1MHz	500ns	2.5ns	2.5ns								

SH00067

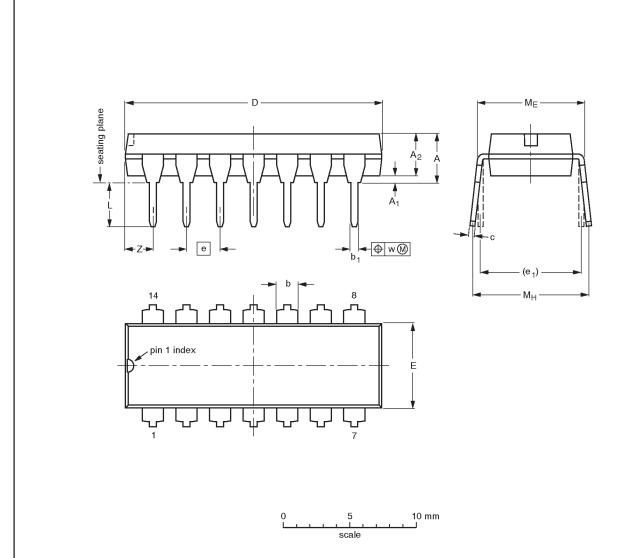
Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

## Quad 2-input NAND gate

74ABT00

#### DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

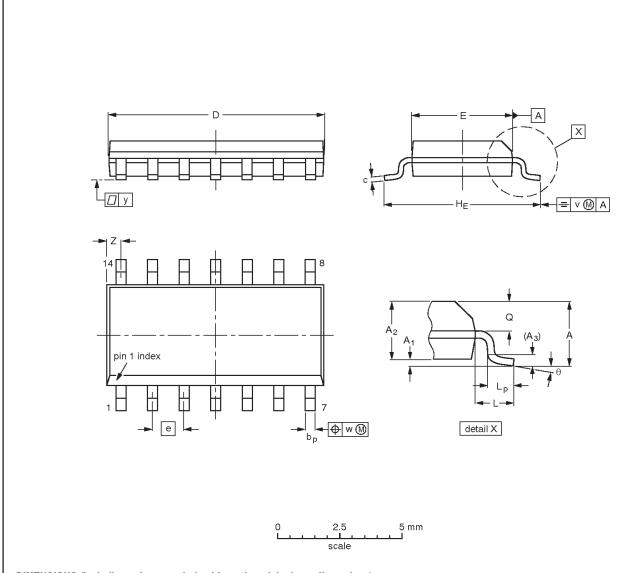
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC		PROJECTION	ISSUE DATE		
SOT27-1	050G04	MO-001AA				<del>92-11-17</del> 95-03-11	

## Quad 2-input NAND gate

74ABT00

#### SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



#### DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	o°

#### Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

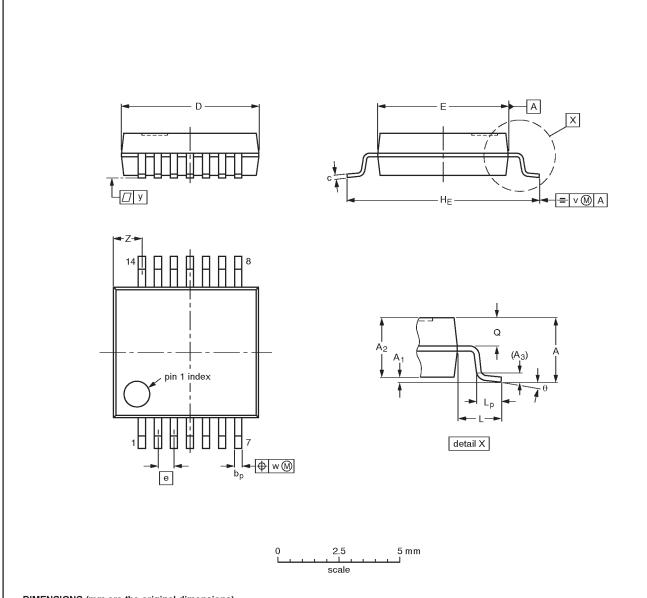
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT108-1	076E06S	MS-012AB				<del>95-01-23</del> 97-05-22	

## Quad 2-input NAND gate

74ABT00

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	<b>A</b> <sub>3</sub>	bp	c	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

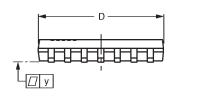
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1990E DATE	
SOT337-1		MO-150AB				<del>-95-02-04</del> 96-01-18	

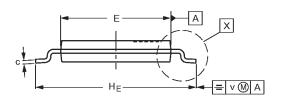
## Quad 2-input NAND gate

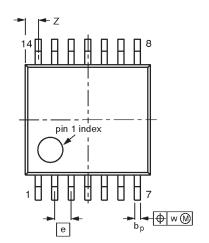
74ABT00

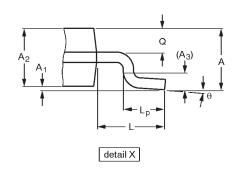
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

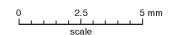
SOT402-1











#### DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A <sub>2</sub>	A <sub>3</sub>	bр	c	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	IEC JEDEC		PROJECTION	ISSUE DATE	١
SOT402-1		MO-153			<del>-94-07-12</del> 95-04-04	

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## Quad 2-input NAND gate

74ABT00

**NOTES** 

### Quad 2-input NAND gate

74ABT00

	DEFINITIONS							
Data Sheet Identification	Product Status	Definition						
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifical may change in any manner without notice.						
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(print code) Date of release: July 1994

Document order number: 9397-750-04854

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